



# THE DATASHEET OF HERF1007G



## 10A, 50V - 1000V High Efficient Rectifier

### FEATURES

- AEC-Q101 qualified available
- High efficiency, low  $V_F$
- High current capability
- High surge current capability
- Low power loss
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

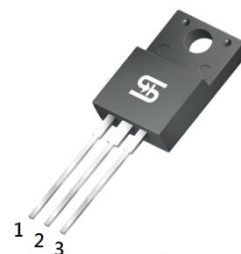
### APPLICATIONS

- DC to DC converter
- Switching mode converters and inverters
- Freewheeling application

### MECHANICAL DATA

- Case: ITO-220AB
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.82g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
$I_F$	10	A
$V_{RRM}$	50 - 1000	V
$I_{FSM}$	125	A
$T_{JMAX}$	150	°C
Package	ITO-220AB	
Configuration	Dual dies	



ITO-220AB



ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)										
PARAMETER	SYMBOL	HERF 1001G	HERF 1002G	HERF 1003G	HERF 1004G	HERF 1005G	HERF 1006G	HERF 1007G	HERF 1008G	UNIT
Marking code on the device		HERF 1001G	HERF 1002G	HERF 1003G	HERF 1004G	HERF 1005G	HERF 1006G	HERF 1007G	HERF 1008G	
Repetitive peak reverse voltage	$V_{RRM}$	50	100	200	300	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	210	280	420	560	700	V
Forward current	$I_F$	10								A
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	$I_{FSM}$	125								A
Junction temperature	$T_J$	-55 to +150								°C
Storage temperature	$T_{STG}$	-55 to +150								°C

<b>THERMAL PERFORMANCE</b>			
<b>PARAMETER</b>	<b>SYMBOL</b>	<b>TYP</b>	<b>UNIT</b>
Junction-to-case thermal resistance	$R_{\theta JC}$	3	°C/W

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^\circ\text{C}$ unless otherwise noted)						
<b>PARAMETER</b>		<b>CONDITIONS</b>	<b>SYMBOL</b>	<b>TYP</b>	<b>MAX</b>	<b>UNIT</b>
Forward voltage per diode <sup>(1)</sup>	HERF1001G	$I_F = 5\text{A}, T_J = 25^\circ\text{C}$	$V_F$	-	1.0	V
	HERF1002G					
	HERF1003G			-	1.3	V
	HERF1004G					
	HERF1005G			-	1.7	V
	HERF1006G					
	HERF1007G					
HERF1008G						
Reverse current @ rated $V_R$ per diode <sup>(2)</sup>		$T_J = 25^\circ\text{C}$	$I_R$	-	10	$\mu\text{A}$
		$T_J = 125^\circ\text{C}$		-	400	$\mu\text{A}$
Junction capacitance per diode	HERF1001G	1MHz, $V_R = 4.0\text{V}$	$C_J$	60	-	pF
	HERF1002G					
	HERF1003G			40	-	pF
	HERF1004G					
	HERF1005G			-	80	ns
	HERF1006G					
	HERF1007G					
HERF1008G						
Reverse recovery time	HERF1001G	$I_F = 0.5\text{A}, I_R = 1.0\text{A}$ $I_{rr} = 0.25\text{A}$	$t_{rr}$	-	50	ns
	HERF1002G					
	HERF1003G			-	80	ns
	HERF1004G					
	HERF1005G			-	80	ns
	HERF1006G					
	HERF1007G					
HERF1008G						

**Notes:**

1. Pulse test with  $PW = 0.3\text{ms}$
2. Pulse test with  $PW = 30\text{ms}$

<b>ORDERING INFORMATION</b>		
<b>ORDERING CODE</b> <sup>(1)(2)</sup>	<b>PACKAGE</b>	<b>PACKING</b>
HERF10xG	ITO-220AB	50 / Tube
HERF10xGH	ITO-220AB	50 / Tube

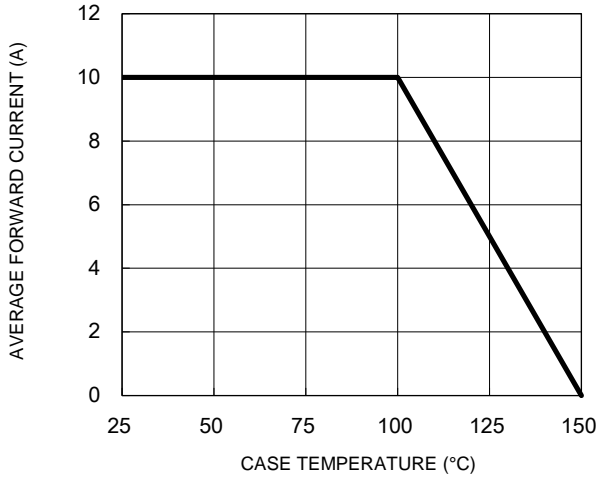
**Notes:**

1. "x" defines voltage from 50V(HERF1001G) to 1000V(HERF1008G)
2. "H" means AEC-Q101 qualified

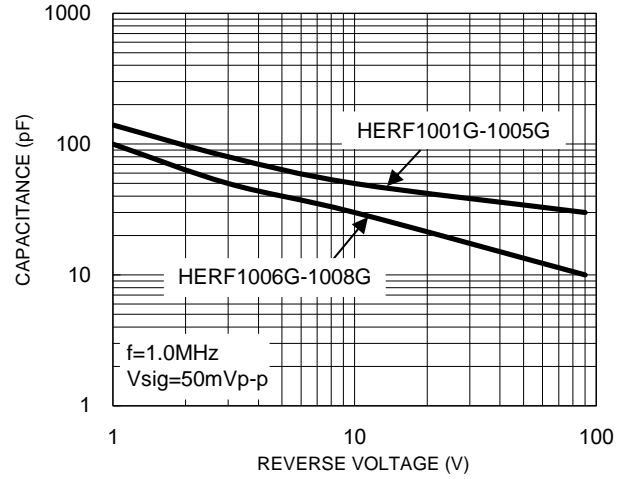
**CHARACTERISTICS CURVES**

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

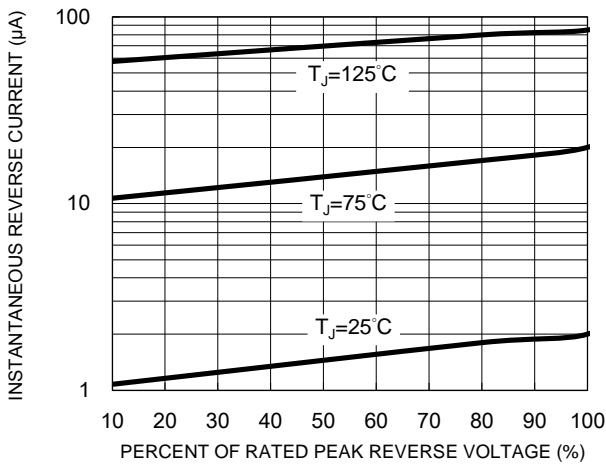
**Fig.1 Forward Current Derating Curve**



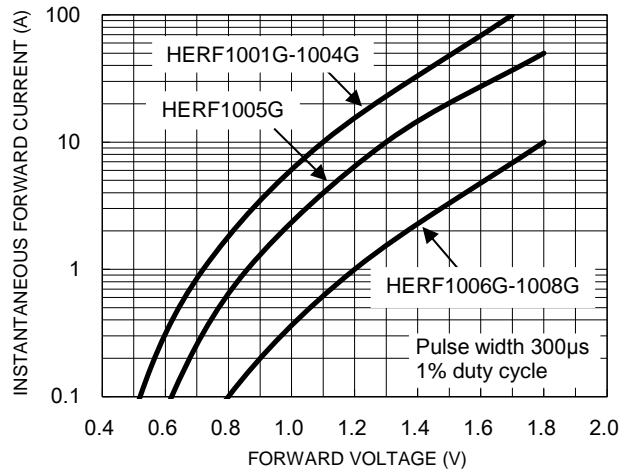
**Fig.2 Typical Junction Capacitance**



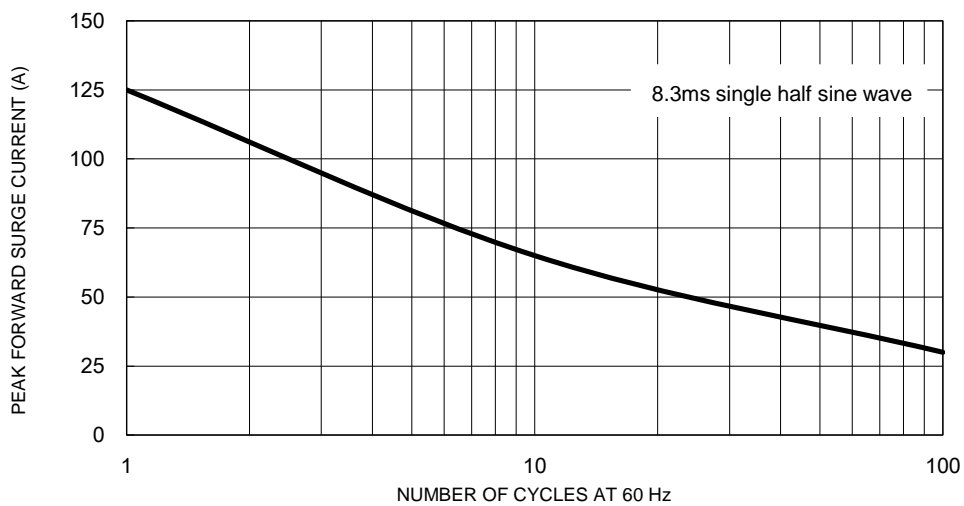
**Fig.3 Typical Reverse Characteristics**



**Fig.4 Typical Forward Characteristics**



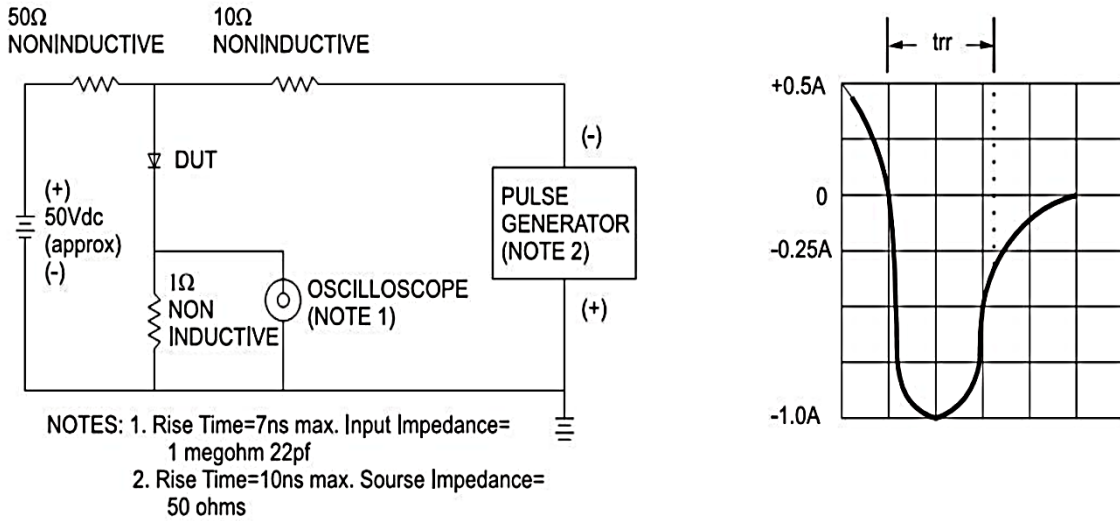
**Fig.5 Maximum Non-Repetitive Forward Surge Current**



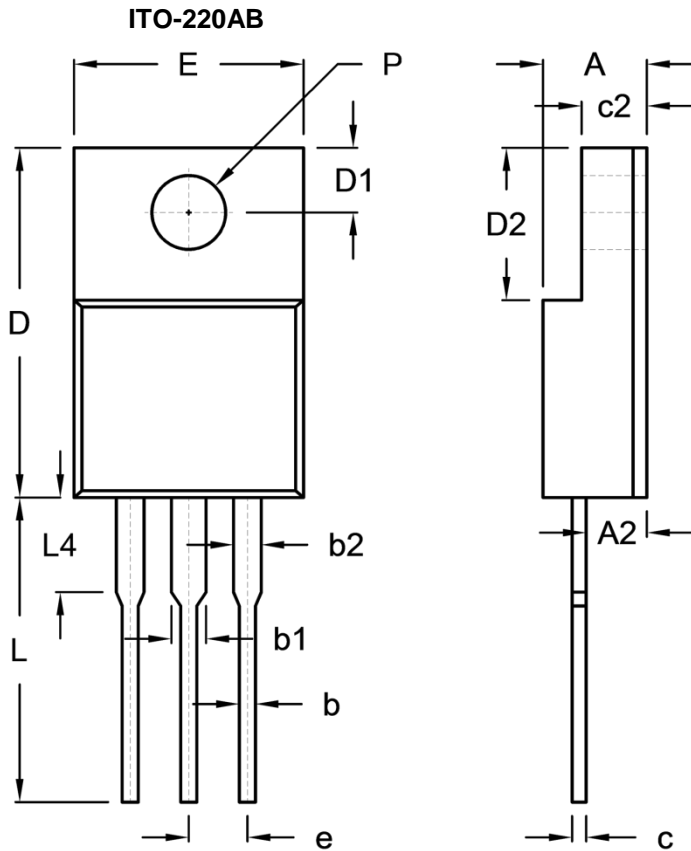
**CHARACTERISTICS CURVES**

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

**Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram**



**PACKAGE OUTLINE DIMENSIONS**



DIM.	Unit (mm)		Unit (inch)	
	Min.	Max.	Min.	Max.
A	4.30	4.70	0.169	0.185
A2	2.30	2.96	0.091	0.117
b	0.50	0.90	0.020	0.035
b1	-	1.80	-	0.071
b2	0.95	1.45	0.037	0.057
c	0.46	0.76	0.018	0.030
c2	2.50	3.16	0.098	0.124
D	14.80	15.50	0.583	0.610
D1	2.40	3.20	0.094	0.126
D2	6.30	6.90	0.248	0.272
E	9.60	10.30	0.378	0.406
e	2.41	2.67	0.095	0.105
L	12.60	13.80	0.496	0.543
L4	-	4.10	-	0.161
P	3.00	3.40	0.118	0.134

**MARKING DIAGRAM**



- P/N = Marking Code
- G = Green Compound
- YWW = Date Code
- F = Factory Code

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